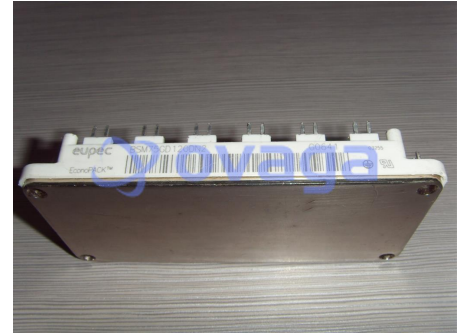


Trans IGBT Module N-CH 1.2KV 103A 21-Pin EconoPACK 3A

Manufacturers	Infineon Technologies Corporation
Package/Case	SMD
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for BSM75GD120DN2 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

BSM75GD120DN2 is a power module designed and manufactured by Infineon Technologies. It is a high-performance IGBT (Insulated Gate Bipolar Transistor) module that consists of a single IGBT and a free-wheeling diode.

Features

IXYS IXGH75N120B3H1

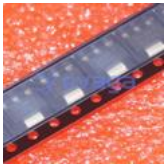
Fuji 2MBI75N-120

Semikron SKM75GB120DN

Toshiba MG75Q2YS40



Related Products



BSP613P

Infineon Technologies Corporation
SOT-223



BSC011N03LS

Infineon Technologies Corporation
PG-TDSON-8



BSB013NE2LXI

Infineon Technologies Corporation
WDSO-2



BSC014N04LSATMA1

Infineon Technologies Corporation
tdson-8



BSC030N08NS5ATMA1

Infineon Technologies Corporation
TDSON-8



BSC026N08NS5ATMA1

Infineon Technologies Corporation
TDSON-8



BSC016N06NSATMA1

Infineon Technologies Corporation
DSON-8



BSC066N06NSATMA1

Infineon Technologies Corporation
TDSON-8